

# Superconductivity in the Endohedral Ga Cluster Compound PdGa<sub>5</sub>

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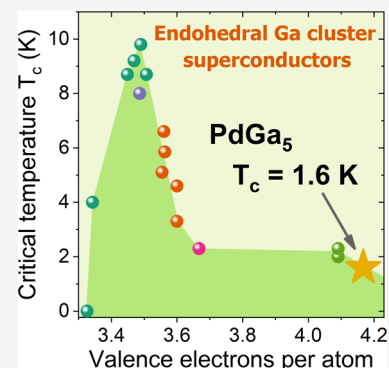
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**ABSTRACT:** Superconductivity is observed below  $T_c = 1.6$  K in an endohedral Ga cluster compound PdGa<sub>5</sub> using magnetization and heat capacity measurements. Electronic structure calculations show that the density of states (DOS) at the Fermi level is dominated by Ga *s* and *p* states and that the overall shape of DOS is similar to what was found in other endohedral Ga cluster superconductors, such as Mo<sub>x</sub>Ga<sub>5x+1</sub>, ReGa<sub>5</sub>, and T<sub>2</sub>Ga<sub>9</sub> ( $T = \text{Rh}$  and Ir). Our results provide a more complete picture of the relationship between the valence electron count and superconductivity in the family of endohedral Ga cluster superconductors.



## INTRODUCTION

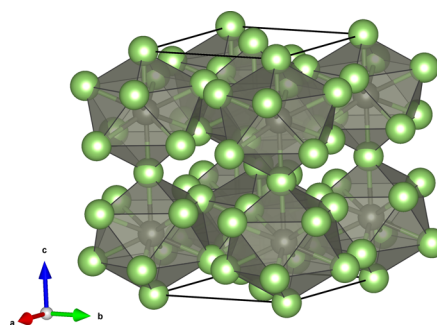
One of the greatest challenges in research on superconducting materials is the lack of robust design guidelines that one could follow to create a superconductor by design. Due to the lack of a complete and universal theory of superconductivity, a significant amount of work has been devoted to finding empirical correlation between the chemical composition, normal (i.e., non-superconducting) state, and the occurrence of superconductivity (see, e.g., refs 1–6).

Endohedral Ga cluster compounds constitute a family of superconductors that recently gained increased attention.<sup>7–25</sup> While crystal structures found in the TM<sub>x</sub>Ga<sub>y</sub> (TM, transition metal) compounds are diverse and rather complex, they can be conveniently described as networks of interconnected endohedral Ga clusters. Xie *et al.*<sup>8</sup> showed the correlation between the cluster connectivity and the valence electron count (VEC).

What is important for searching new superconducting materials is that endohedral Ga cluster compounds also show the relationship between the critical temperature ( $T_c$ ) and VEC,<sup>8</sup> alike other groups of superconducting materials,<sup>26</sup> such as metallic elements,<sup>1,27,28</sup> binary A-15 phases,<sup>1,27,29</sup> Heusler compounds,<sup>30,31</sup> and high-entropy alloys.<sup>32,33</sup>

In the case of endohedral gallides, the highest  $T_c$  values were reported for Mo<sub>8</sub>Ga<sub>41</sub> ( $T_c = 9.8$  K) and Mo<sub>6</sub>Ga<sub>31</sub> ( $T_c = 8.0$  K) with VEC  $\approx 21.4$  and 21.5 per transition metal atom, respectively.<sup>8</sup> For a larger VEC, the critical temperatures are much lower, namely,  $T_c = 2.3$  K for ReGa<sub>5</sub> (VEC = 22) and  $T_c = 2.0$  for Rh<sub>2</sub>Ga<sub>9</sub> (VEC = 22.5).<sup>7,8</sup>

PdGa<sub>5</sub> is an endohedral cluster compound that has 25 valence electrons and a mixed edge- and vertex-sharing manner of cluster connection. The unit cell of PdGa<sub>5</sub> with clusters of gallium around palladium atoms is shown in Figure 1. Each Pd



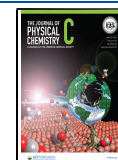
**Figure 1.** Unit cell of PdGa<sub>5</sub> (Ga atoms, green; Pd, gray). Vertex-sharing PdGa<sub>10</sub> clusters are shown in gray.

atom is surrounded by 10 Ga atoms. Pd atoms in PdGa<sub>5</sub> are well separated with the closest Pd–Pd distance of ca. 4.6 Å; thus, direct Pd–Pd bonding is negligible. Such a situation is also found in other endohedral Ga cluster superconductors, such as Mo<sub>8</sub>Ga<sub>41</sub>,<sup>15,20,34,35</sup> Mo<sub>6</sub>Ga<sub>31</sub>,<sup>22,36</sup> Mo<sub>4</sub>Ga<sub>21</sub>,<sup>14,17</sup> and TM<sub>2</sub>Ga<sub>9</sub><sup>7</sup> families. However in ReGa<sub>5</sub>,<sup>8</sup> the Re–Re distance is clearly within the direct bonding range. The PdGa<sub>10</sub> units form a three-dimensional vertex-sharing network with sizable voids between the clusters. The crystal structure of PdGa<sub>5</sub> has been thoroughly studied and discussed by Grin *et al.*<sup>37</sup>

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The number of valence electrons per transition metal atom situates PdGa<sub>5</sub> in the rightmost part of the  $T_c$  vs VEC diagram proposed by Xie *et al.*<sup>8</sup> with no superconducting transition down to 1.8 K.

In this work, we have revisited PdGa<sub>5</sub> to investigate its properties below 1.8 K. Flux-grown single crystals of this material were examined by means of magnetic susceptibility and heat capacity measurements. The compound was found to superconduct below  $T_c = 1.6$  K, thus supporting the VEC- $T_c$  relationship suggested for the endohedral gallide materials.

## MATERIALS AND METHODS

Single crystals of PdGa<sub>5</sub> were synthesized using the self-flux method.<sup>38</sup> Palladium powder (Mennica-Metale, Poland, 99.95%) and pieces of a gallium ingot (Alfa Aesar, 99.99%) were inserted into an alumina crucible in a 3:22 molar ratio. Another crucible and a frit disk were used to facilitate the separating flux from the crystals.<sup>39</sup> The set was closed in a quartz ampoule filled with Ar gas. The ampoule was placed in a box furnace, heated up to 300 °C, kept at this temperature for 12 h, and cooled with a rate of 1 °C/h down to 100 °C. At this temperature, the excess flux was centrifuged. The crystals obtained were small (about 0.5 mm in the longest dimension), silver, and shiny. As the masses of individual crystals were not sufficient, clusters of randomly oriented single crystals were used for measurements of physical properties (magnetization and heat capacity).

Powder X-ray diffraction (PXRD) was performed using a Bruker D8 Focus diffractometer with Cu K $\alpha$  radiation on several single crystals crushed and fine-ground in an agate mortar. LeBail profile matching, performed using the FullProf package,<sup>40</sup> confirmed the tetragonal structure of PdGa<sub>5</sub>.

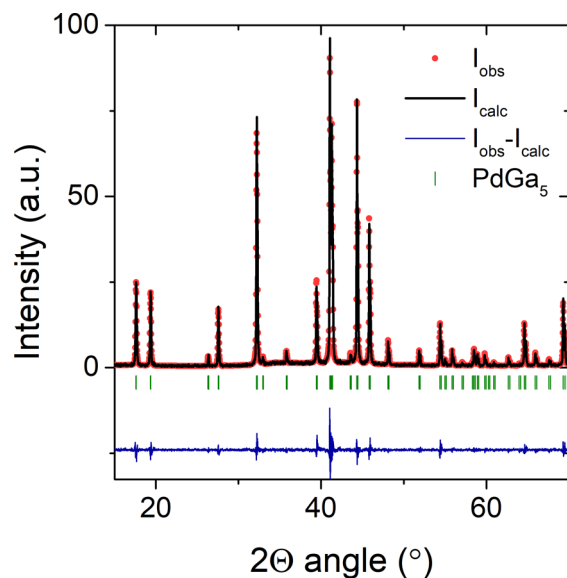
Magnetic susceptibility and magnetization measurements were carried out in the temperature range of 0.5–1.6 K and in magnetic fields up to  $\mu_0 H = 10$  mT employing a Quantum Design MPMS-XL superconducting quantum interference device (SQUID) magnetometer equipped with a <sup>3</sup>He refrigerator.

Heat capacity measurements were done in the temperature range of 0.5–3 K in applied magnetic fields up to  $\mu_0 H = 10$  mT using a Quantum Design physical property measurement system (PPMS) with a dilution refrigerator option employing the semi-adiabatic pulse technique.

Electronic structure calculations were done with the Quantum Espresso package<sup>41–43</sup> employing the projector-augmented wave (PAW)<sup>44,45</sup> sets from the PSlab database<sup>46</sup> and the Perdew–Burke–Ernzerhof generalized gradient approximation<sup>47</sup> exchange–correlation potential. Wave function and charge density cutoffs were set to 62 and 500 Ry, respectively. The experimental primitive cell dimensions and atomic positions were relaxed using the Broyden–Fletcher–Goldfarb–Shanno algorithm. For calculations, a  $6 \times 6 \times 7$   $k$ -point mesh was used. The symmetrized unit cell parameters were calculated from the relaxed primitive cell using the FINDSYM program of the ISOTROPY suite<sup>48</sup> (see Table S1 of the Supporting Information). Crystal orbital Hamiltonian population (COHP)<sup>49,50</sup> analysis was performed using the LOBSTER code.<sup>51</sup>

## RESULTS AND DISCUSSION

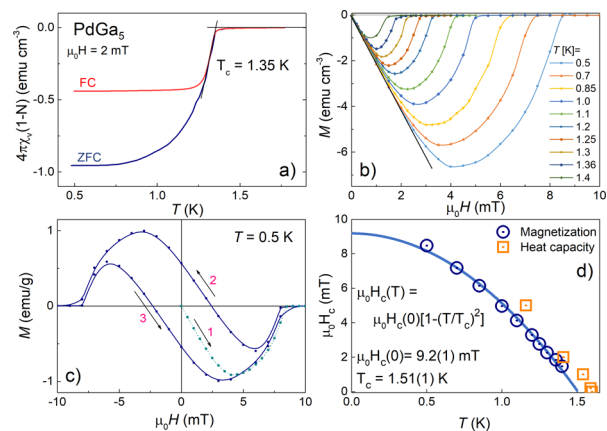
The measured PXRD pattern of PdGa<sub>5</sub> is presented in Figure 2. All of the observed reflections can be indexed with a



**Figure 2.** PXRD pattern for crushed PdGa<sub>5</sub> single crystals. Observed data are marked with red dots. The LeBail fit is presented as black solid lines, and the difference between the observed and calculated profile is shown with blue lines. Bragg positions are marked with green ticks.

tetragonal (space group  $I4/mcm$ ) unit cell. The detailed results of the LeBail refinement are given in Table S2 of the Supporting Information. The derived unit cell parameters  $a = 6.4347(1)$  Å and  $c = 9.9871(2)$  Å are in good agreement with the values reported by Grin *et al.*<sup>52</sup>

The results of magnetization measurements are presented in Figure 3a–d. The low-temperature zero-field-cooled (ZFC)



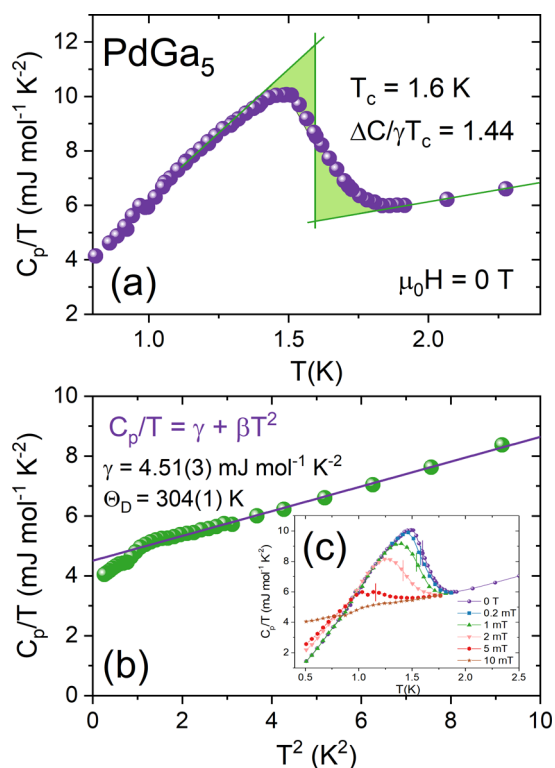
**Figure 3.** Magnetic data of PdGa<sub>5</sub>. (a) ZFC and FC magnetic susceptibility measured in  $\mu_0 H = 2$  mT, (b) magnetization isotherms, (c) hysteresis loop taken at  $T = 0.5$  K, and (d) critical field vs temperature, obtained from magnetization (blue) and heat capacity (orange) data.

and field-cooled (FC) magnetic susceptibility data are shown in Figure 3a. After accounting for the demagnetization effect (discussed below), the ZFC susceptibility  $\chi_V$  at  $T = 0.5$  K is close to  $-1/4\pi$ , showing that the sample is in a fully diamagnetic (Meissner) state. The bifurcation between the ZFC and FC curves indicates a magnetic flux pinning on crystal defects. The critical temperature, determined from the ZFC data as a point at which the steepest slope of  $\chi_V(T)$

intersects the normal state susceptibility,<sup>53</sup> amounts to  $T_c = 1.35$  K. This value is somewhat smaller than that obtained from a zero-field heat capacity measurement (see below) because of the rather low critical field in PdGa<sub>5</sub>.

The sample demagnetization factor  $N$  is determined using the data shown in Figure 3b. The points collected at the lowest temperature were fitted with a linear function  $M = aH + b$  (black solid line), assuming a perfect diamagnetic response. From the equation  $-a = \frac{1}{4\pi(1-N)}$ ,  $N = 0.62$  was derived, in a reasonable agreement with the sample geometry.<sup>54</sup> The field values at which the susceptibility reaches zero (suppression of the Meissner state) were taken as the critical fields  $\mu_0 H_c(T)$  and plotted as a function of temperature, as shown in Figure 3d. The so-obtained data were fitted with the formula  $\mu_0 H_c(T) = \mu_0 H_c(0)[1 - (T/T_c)^2]$  (orange solid line), yielding  $\mu_0 H_c(0) = 9.2(1)$  mT. The critical temperature estimated from the same fit is  $T_c = 1.51$  K, i.e., close to the value determined from the heat capacity data (see below). Figure 3c presents the magnetization isotherm taken at  $T = 0.5$  K. The shape of the  $M$  vs  $H$  loop differs from what one expects for a typical type-II superconductor but is consistent with type-I superconductivity with significant contribution of demagnetization effects (see, e.g., ref 55).

The results of heat capacity measurements are shown in Figure 4a,b. From the equal entropy construction procedure shown in Figure 4a, the critical temperature was determined as  $T_c = 1.6$  K, and the superconducting jump was estimated to be  $\Delta C_p/T_c = 6.49$  mJ mol<sup>-1</sup> K<sup>-2</sup>. As can be inferred from Figure



**Figure 4.** Heat capacity data for PdGa<sub>5</sub>. (a) Equal entropy analysis of the superconducting anomaly. (b) Normal state specific heat (in an applied field of  $\mu_0 H = 10$  mT) described by the low-temperature expansion of the Debye model (solid straight line). Inset (c): low-temperature specific heat measured in different applied magnetic fields.

4c, the  $C_p$  anomaly is suppressed by the external magnetic field in a manner consistent with the magnetization data (see Figure 3).

In the normal state (the data were measured in  $\mu_0 H = 10$  mT), the heat capacity of PdGa<sub>5</sub> can be described with the Debye formula  $C_p/T = \gamma + \beta T^2$ , where  $\gamma$  is the Sommerfeld electronic coefficient and the second term accounts for the phonon contribution. The least-squares fit shown in Figure 4b yields  $\gamma = 4.51(3)$  mJ mol<sup>-1</sup> K<sup>-2</sup> and  $\beta = 0.413(6)$  mJ mol<sup>-2</sup> K<sup>-4</sup>. Using the relation

$$\Theta_D = \sqrt[3]{\frac{12\pi^4 nR}{5\beta}}$$

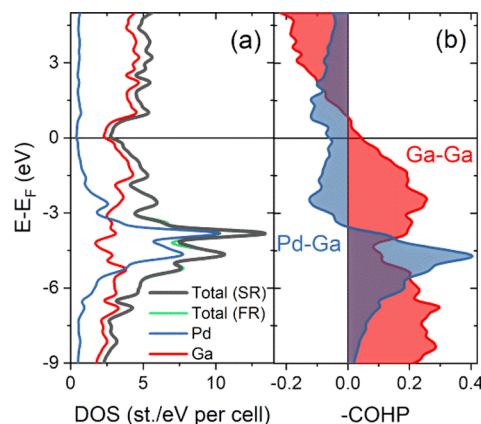
where  $n$  is the number of atoms per formula unit (here,  $n = 6$ ) and  $R$  is the gas constant ( $R = 8.31$  J mol<sup>-1</sup> K<sup>-1</sup>); one finds the Debye temperature  $\Theta_D = 304(1)$  K. Notably, the normalized heat capacity jump  $\Delta C_p/\gamma T_c = 1.44$  estimated for PdGa<sub>5</sub> is very close to the value predicted by the Bardeen–Cooper–Schrieffer (BCS) theory for the weak-coupling limit.

Taking the  $\Theta_D$  and  $T_c$  values estimated from the heat capacity measurement and using the inverted McMillan formula<sup>56</sup>

$$\lambda_{\text{el-ph}} = \frac{1.04 + \mu^* \ln\left(\frac{\Theta_D}{1.45T_c}\right)}{(1 - 0.62\mu^*) \ln\left(\frac{\Theta_D}{1.45T_c}\right) - 1.04}$$

where  $\mu^*$  is the Coulomb pseudopotential parameter (in typical superconductors,  $\mu^*$  usually equals to 0.10–0.15; here,  $\mu^* = 0.13$  was assumed), the electron–phonon coupling constant was estimated as  $\lambda_{\text{el-ph}} = 0.49$ , indicative of the weak coupling regime.

As depicted in Figure 5a, the electronic density of states at the Fermi energy  $E_F$  is dominated by Ga  $s$  and  $p$  orbitals with



**Figure 5.** Density of states (a) and crystal orbital Hamiltonian population (b) calculated for PdGa<sub>5</sub>. The COHP curves are shown as an average over all Pd–Ga (20 per cell) or Ga–Ga pairs (36 per cell).

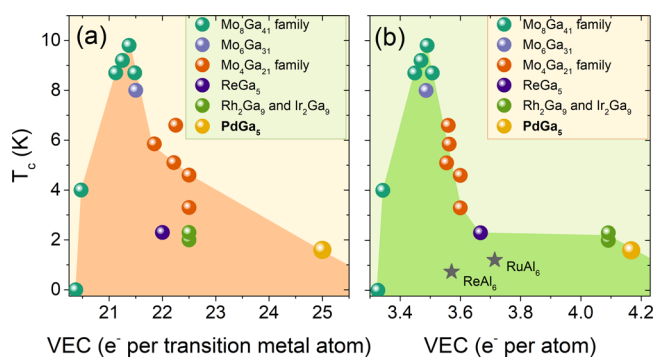
only about 14% contribution due to Pd atoms. The Pd  $d$  states are mostly occupied, lying over 3 eV below  $E_F$ . Remarkably, the Fermi level in PdGa<sub>5</sub> is situated within a pseudogap.

Despite structural differences, the overall character of the DOS is remarkably similar to other endohedral Ga cluster superconductors.<sup>8,10,57,58</sup> In each of them, transition metal  $d$  states are almost fully occupied, being located 2–3 eV below

$E_F$ . This similarity of the electronic structures allows comparing this structurally diverse group on a common basis of the valence electron count.

The COHP calculations (Figure 5b) show that the DOS ( $E_F$ ) has a significant contribution of Pd–Ga antibonding states ( $-\text{COHP} < 0$  above  $-3$  eV), while Ga–Ga interactions have (on average) a bonding character up to ca. 0.5 eV above  $E_F$ . In our recent study of an endohedral Al superconductor  $\text{RuAl}_6$ , we demonstrated that the occupation of antibonding states results in an electronic structure instability, in this case manifesting itself as a superconducting transition.<sup>59</sup> Thus, a slight electron doping of  $\text{PdGa}_5$ , shifting  $E_F$  toward the Ga–Ga antibonding range, may result in an increase of  $T_c$ .

The total VEC in  $\text{PdGa}_5$  is 25 per Pd, equivalent to ca. 4.17 per atom, making this material the most electron-rich endohedral Ga cluster compound. A number of endohedral Ga superconductors were reported since Xie *et al.*<sup>8</sup> have suggested the relationship between  $T_c$  and VEC per TM atom.<sup>10,14,15,17</sup> Inclusion of these recently reported phases provides further support for that correlation (see Figure 6a).



**Figure 6.** Relationship between the  $T_c$  and valence electron count in endohedral gallide superconductors. Within the  $\text{Mo}_8\text{Ga}_{41}$  family, the VEC was changed by partial substitution in both Mo (with V)<sup>11,20</sup> and Ga sites (with Sn and Zn).<sup>13–15</sup> The  $\text{Mo}_4\text{Ga}_{21}$  family consists of five reported members with Ga partially substituted by chalcogens, Sn, or Sb.<sup>14,17</sup> In panel (a), the total number of valence electrons is divided by the number of transition metal atoms (VEC/TM atom, as was proposed by Xie *et al.*).<sup>8</sup> Panel (b) shows the VEC divided by the total number of atoms (VEC/atom). Two endohedral aluminide superconductors,  $\text{RuAl}_6$  ( $T_c = 1.2$  K)<sup>59</sup> and  $\text{ReAl}_6$  ( $T_c = 0.74$  K),<sup>60</sup> are also included in panel (b) for comparison.

However, most of the known superconducting Ga endohedral cluster compounds have only up to 22.5 electrons per TM atom, limiting the possibility to extend the conclusions to  $\text{PdGa}_5$  with VEC/TM atom = 25.

If the  $T_c$  data is plotted against the VEC divided per total number of atoms (see Figure 6b), then  $\text{PdGa}_5$  lies close to  $\text{Rh}_2\text{Al}_9$  and  $\text{Ir}_2\text{Al}_9$  compounds with slightly higher  $T_c = 2.0$  and 2.3 K, respectively. Remarkably, in such a representation,  $\text{ReGa}_5$  seems to follow an almost linear decrease of  $T_c$  between VEC = 3.49 per atom ( $\text{Mo}_8\text{Ga}_{41}$ ,  $T_c = 9.8$ ) and VEC = 3.67 per atom ( $\text{ReGa}_5$ ,  $T_c = 2.3$  K).

No endohedral Ga cluster superconductors are known with VEC/atom values between 3.67 and 4.09. In our recent study on  $\text{RuAl}_6$  (VEC/atom = 3.71), we suggested that electron doping might increase its  $T_c$ .<sup>59</sup> In the case of  $\text{PdGa}_5$ , the VEC- $T_c$  correlation shown in Figure 6a,b would suggest that electron doping should reduce the  $T_c$ , but superconductivity can possibly be enhanced by hole doping. The synthesis and

characterization of electron-doped  $\text{ReGa}_5$  or hole-doped  $\text{TM}_2\text{Ga}_9$  and  $\text{PdGa}_5$  are thus of high interest as they could provide further data to elucidate the relationship between  $T_c$  and VEC over a broader range.

## CONCLUSIONS

We have studied the low-temperature properties of the endohedral Ga cluster compound  $\text{PdGa}_5$  and found it to become superconducting below  $T_c = 1.6$  K. The low critical field and the shape of the  $M(H)$  loop suggest that  $\text{PdGa}_5$  is a type-I superconductor, but further studies are necessary to elucidate this point.

The electronic structure calculations revealed that, despite structural differences,  $\text{PdGa}_5$  is similar to other endohedral Ga cluster superconductors. The observed  $T_c$  value fits into the VEC- $T_c$  correlation suggested before for this family,<sup>8</sup> highlighting its robustness. Electron and hole doping experiments on  $\text{ReGa}_5$ ,  $\text{TM}_2\text{Ga}_9$ , and  $\text{PdGa}_5$  should provide further insight into the observed VEC- $T_c$  relationship.

## ASSOCIATED CONTENT

### Supporting Information

The Supporting Information is available free of charge at <https://pubs.acs.org/doi/10.1021/acs.jpcc.1c03615>.

Results of LeBail analysis of PXRD data and DFT-relaxed structural parameters for  $\text{PdGa}_5$  (PDF)

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### Author Contributions

The manuscript was written through contributions of all authors.

### Notes

The authors declare no competing financial interest.

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## ABBREVIATIONS

COHP, crystal orbital Hamilton population; DOS, density of (electronic) states; FC, field-cooled; PXRD, powder X-ray diffraction; SC, superconductor; TM, transition metal; VEC, valence electron count; ZFC, zero-field-cooled

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